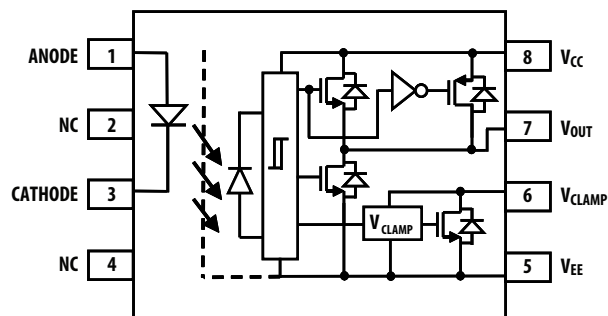## Functional Diagram

NOTE   A 1-µF bypass capacitor must be connected between pins V_{CC} and V_{EE}.

Truth Table

LED	$V_{CC} - V_{EE}$ "POSITIVE GOING" (that is, TURN-ON)	$V_{CC} - V_{EE}$ "NEGATIVE GOING" (that is, TURN-OFF)	V_O	V_{CLAMP}
OFF	0–30V	0–30V	LOW	LOW
ON	0–11V	0–9.5V	LOW	LOW
ON	11–13.5V	9.5–12V	TRANSITION	TRANSITION
ON	13.5–30V	12–30V	HIGH	Hi-Z

Ordering Information

ACPL-H342 is UL Recognized with 3750 V_{RMS} for 1 minute per UL1577.
ACPL-K342 is UL Recognized with 5000 V_{RMS} for 1 minute per UL1577.

Part Number	Option (RoHS Compliant)	Package	Surface Mount	Tape and Reel	UL 5000 V_{RMS}/ 1 Minute Rating	IEC/EN/DIN EN 60747-5-5	Quantity
ACPL-H342	-000E	Stretched SO-8	X				80 per tube
	-500E		X	X			1000 per reel
	-060E		X			X	80 per tube
	-560E		X	X		X	1000 per reel
ACPL-K342	-000E	Stretched SO-8	X		X		80 per tube
	-500E		X	X	X		1000 per reel
	-060E		X		X	X	80 per tube
	-560E		X	X	X	X	1000 per reel

Example 1:

ACPL-H342-560E to order product of Stretched SO-8 Surface Mount package in Tape and Reel packaging with IEC/EN/DIN EN 60747-5-5 Safety Approval and RoHS compliant.
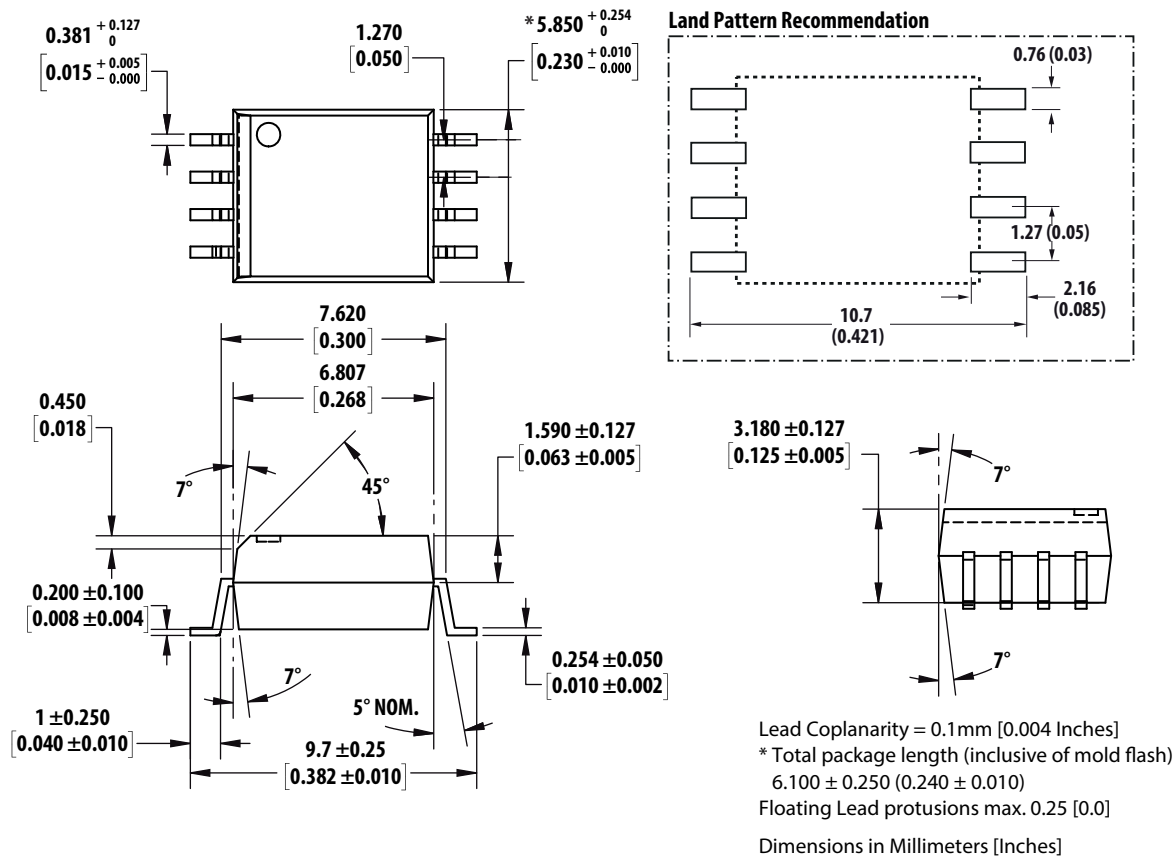
Example 2:

ACPL-K342-000E to order product of Stretched SO-8 Surface Mount package in Tube packaging with UL 5000 V_{RMS}/1 minute and RoHS compliant.
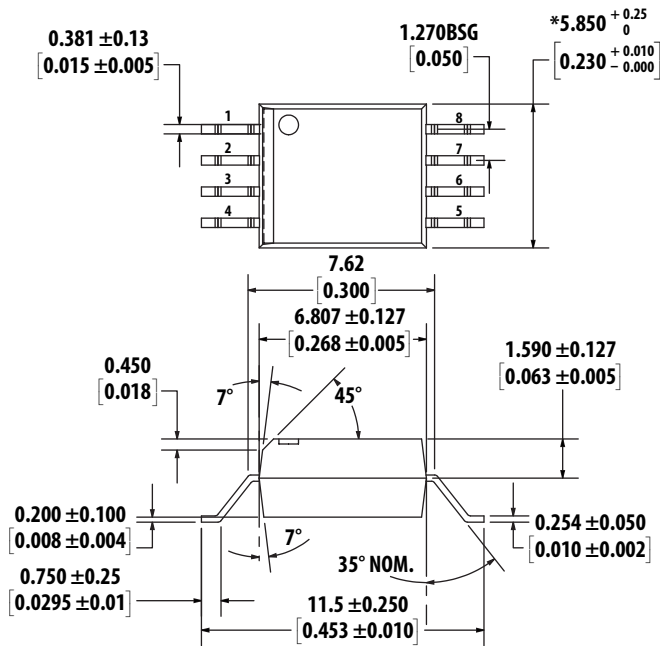
Option data sheets are available. Contact your Broadcom sales representative or authorized distributor for information.
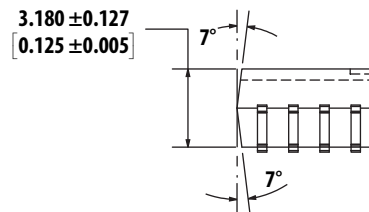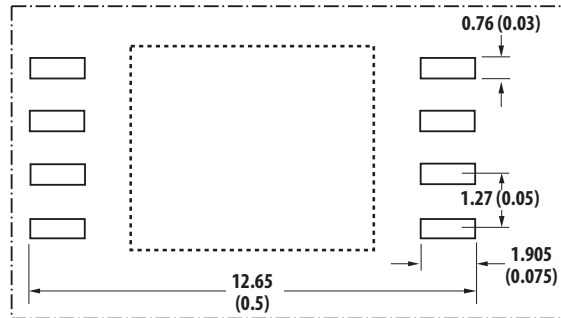
Package Outline Drawings

ACPL-H342 Outline Drawing

$0.381 \, ^{+0.127}_{0}$
$\left[0.015 \, ^{+0.005}_{-0.000} \right]$

1.270
[0.050]

$* \, 5.850 \, ^{+0.254}_{0}$
$\left[0.230 \, ^{+0.010}_{-0.000} \right]$

Land Pattern Recommendation

0.76 (0.03)

1.27 (0.05)

2.16 (0.085)

10.7 (0.421)

7.620
[0.300]

6.807
[0.268]

0.450
[0.018]

7°

45°

1.590 ±0.127
[0.063 ±0.005]

3.180 ±0.127
[0.125 ±0.005]

7°

0.200 ±0.100
[0.008 ±0.004]

7°

5° NOM.

0.254 ±0.050
[0.010 ±0.002]

7°

1 ±0.250
[0.040 ±0.010]

9.7 ±0.25
[0.382 ±0.010]

Lead Coplanarity = 0.1mm [0.004 Inches]
* Total package length (inclusive of mold flash)
  6.100 ± 0.250 (0.240 ± 0.010)
Floating Lead protusions max. 0.25 [0.0]

Dimensions in Millimeters [Inches]

ACPL-K342 Outline Drawing

0.381 ±0.13
[0.015 ±0.005]

1.270BSG
[0.050]

*5.850 $^{+\,0.25}_{\ 0}$
[0.230 $^{+\,0.010}_{-\,0.000}$]

Land Pattern Recommendation

0.76 (0.03)

1.27 (0.05)

1.905 (0.075)

12.65 (0.5)

1 8
2 7
3 6
4 5

7.62
[0.300]

6.807 ±0.127
[0.268 ±0.005]

1.590 ±0.127
[0.063 ±0.005]

0.450
[0.018]

7°   45°

3.180 ±0.127
[0.125 ±0.005]

7°

0.200 ±0.100
[0.008 ±0.004]

7°

0.254 ±0.050
[0.010 ±0.002]

0.750 ±0.25
[0.0295 ±0.01]

35° NOM.

11.5 ±0.250
[0.453 ±0.010]

7°

Lead Coplanarity = 0.1mm [0.004 Inches]
* Total package length (inclusive of mold flash)
   6.100 ± 0.250 (0.240 ± 0.010)
Floating Lead protusions max. 0.25 [0.0]

Dimensions in Millimeters [Inches]

Recommended Pb-Free IR Profile

Recommended reflow condition as per JEDEC Standard, J-STD-020 (latest revision). Non- Halide Flux should be used.

Regulatory Information

The ACPL-H342 / ACPL-K342 is approved by the following organizations:

- UL

  Recognized under UL 1577, component recognition program up to V_{ISO} = 3750 V_{RMS} (ACPL-H342) and V_{ISO} = 5000 V_{RMS} (ACPL-K342), File 55361.

- CSA

  CSA Component Acceptance Notice #5, File CA 88324.

- IEC/EN/DIN EN 60747-5-5 (ACPL-H342/K342 Option 060 Only)

  Maximum Working Insulation Voltage V_{IORM} = 891V_{peak} (ACPL-H342) and V_{IORM} = 1140 V_{peak} (ACPL-K342).

IEC/EN/DIN EN 60747-5-5 Insulation Characteristics (ACPL-H342 / ACPL-K342 Option 060)

Description	Symbol	ACPL-H342 Option 060	ACPL-K342 Option 060	Units
Installation classification per DIN VDE 0110/39, Table 1f				
or rated mains voltage ≤ 150 V_{rms}		I – IV	I – IV	
for rated mains voltage ≤ 300 V_{rms}		I – IV	I – IV	
for rated mains voltage ≤ 450 V_{rms}		I – III	I – IV	
for rated mains voltage ≤ 600 V_{rms}		I – III	I – IV	
for rated mains voltage ≤ 1000 V_{rms}			I – III	
Climatic Classification		40/105/21	40/105/21	
Pollution Degree (DIN VDE 0110/39)		2	2	
Maximum Working Insulation Voltage	V_{IORM}	891	1140	Vpeak
Input to Output Test Voltage, Method b[a] $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with t_m=1s, Partial discharge < 5 pC	V_{PR}	1671	2137	Vpeak
Input to Output Test Voltage, Method a[a] $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test, t_m=10s, Partial discharge < 5 pC	V_{PR}	1426	1824	Vpeak
Highest Allowable Overvoltage[a] (Transient Overvoltage t_{ini} = 60s)	V_{IOTM}	6000	8000	Vpeak
Safety-limiting values – maximum values allowed in the event of a failure				
Case Temperature	T_S	175	175	°C
Input Current	$I_{S, INPUT}$	230	230	mA
Output Power	$P_{S, OUTPUT}$	600	600	mW
Insulation Resistance at T_S, V_{IO} = 500 V	R_S	>10^9	>10^9	Ω

a.   Refer to IEC/EN/DIN EN 60747-5-5 Optoisolator Safety Standard section of the *Broadcom Regulatory Guide to Isolation Circuits*, AV02-2041EN, for a detailed description of Method a and Method b partial discharge test profiles.

NOTE   These optocouplers are suitable for "safe electrical isolation" only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits. Surface mount classification is Class A in accordance with CECC 00802.

Insulation and Safety Related Specifications

Parameter	Symbol	ACPL-H342	ACPL-K342	Units	Conditions
Minimum External Air Gap (Clearance)	L(101)	7.0	8.0	mm	Measured from input terminals to output terminals, shortest distance through air.
Minimum External Tracking (Creepage)	L(102)	8.0	8.0	mm	Measured from input terminals to output terminals, shortest distance path along body.
Minimum Internal Plastic Gap (Internal Clearance)		0.08	0.08	mm	Through insulation distance conductor to conductor, usually the straight line distance thickness between the emitter and detector.
Tracking Resistance (Comparative Tracking Index)	CTI	> 175	> 175	V	DIN IEC 112/VDE 0303 Part 1
Isolation Group		IIIa	IIIa		Material Group (DIN VDE 0110, 1/89, Table 1)

NOTE All Broadcom data sheets report the creepage and clearance inherent to the optocoupler component itself. These dimensions are needed as a starting point for the equipment designer when determining the circuit insulation requirements. However, once mounted on a printed circuit board, minimum creepage and clearance requirements must be met as specified for individual equipment standards. For creepage, the shortest distance path along the surface of a printed circuit board between the solder fillets of the input and output leads must be considered (the recommended land pattern does not necessarily meet the minimum creepage of the device). There are recommended techniques such as grooves and ribs which may be used on a printed circuit board to achieve desired creepage and clearances. Creepage and clearance distances will also change depending on factors such as pollution degree and insulation level.

Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Units	Note
Storage Temperature	T_S	−55	125	°C	
Operating Temperature	T_A	−40	105	°C	
Output IC Junction Temperature	T_J	—	125	°C	
Average Input Current	$I_{F(AVG)}$	—	25	mA	a
Peak Transient Input Current (<1 ms pulse width, 300 pps)	$I_{F(TRAN)}$	—	1	A	
Reverse Input Voltage	V_R	—	5	V	
"High" Peak Output Current	$I_{OH(PEAK)}$	—	2.5	A	b
"Low" Peak Output Current	$I_{OL(PEAK)}$	—	2.5	A	b
Peak Clamp Sink Current	I_{CLAMP}	—	2.5	A	b
Total Output Supply Voltage	$(V_{CC} - V_{EE})$	0	35	V	
Output Voltage	$V_{O(PEAK)}$	−0.5	V_{CC}	V	
Output IC Power Dissipation	P_O	—	500	mW	c
Total Power Dissipation	P_T	—	550	mW	d
Lead Solder Temperature	260°C for 10s., 1.6 mm below seating plane				

a. Derate linearly above 70°C free-air temperature at a rate of 0.3 mA/°C.

b. Maximum pulse width = 10 µs.

c. Derate linearly above 85°C free-air temperature at a rate of 12.5 mW/°C.

d. Derate linearly above 85°C free-air temperature at a rate of 13.75 mW/°C. The maximum LED junction temperature should not exceed 125°C.

Recommended Operating Conditions

Parameter	Symbol	Min.	Max.	Units	Note
Operating Temperature	T_A	−40	105	°C	
Output Supply Voltage	$(V_{CC} - V_{EE})$	15	30	V	
Input Current (ON)	$I_{F(ON)}$	7	16	mA	
Input Voltage (OFF)	$V_{F(OFF)}$	−3.6	0.8	V	

Electrical Specifications (DC)

Unless otherwise noted, all typical values are at $T_A = 25°C$, $V_{CC} - V_{EE} = 30V$, V_{EE} = Ground; all Minimum/Maximum specifications are at recommended operating conditions ($T_A = -40°C$ to $105°C$, $I_{F(ON)} = 7$ mA to 16 mA, $V_{F(OFF)} = -3.6V$ to 0.8V, $V_{CC} = 15V$ to 30V, V_{EE} = Ground).

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions	Figure	Note
High Level Peak Output Current	I_{OH}	−0.5	−1.2	—	A	$V_O = V_{CC} - 4V$	3, 4, 23	a
		−2.0	—	—	A	$V_O = V_{CC} - 15V$		b
Low Level Peak Output Current	I_{OL}	0.5	2.7	—	A	$V_O = V_{EE} + 2.5V$	6, 7, 24	a
		2.0	—	—	A	$V_O = V_{EE} + 15V$		b
High Output Transistor RDS(ON)	$R_{DS,OH}$	—	2.6	5.0	Ω	$I_{OH} = -2.0A$	8	
Low Output Transistor RDS(ON)	$R_{DS,OL}$	—	0.8	2.0	Ω	$I_{OL} = 2.0A$	9	
Clamp Output Peak Current	I_{CLAMP}	1.0	2.5	—	A	$V_O = V_{EE} + 2.5V$	14, 16, 27	b
Clamp Pin Threshold	V_{tCLAMP}	—	2.3	—	V		15,16, 28	
Clamp Output Transistor RDS(ON)	$R_{DS,CLAMP}$	—	0.8	2.0	Ω	$I_{CLAMP} = 1.5A$		
High Level Output Voltage	V_{OH}	$V_{CC} - 2.0$	$V_{CC} - 0.80$	—	V	$I_O = -100$ mA	2, 4, 25	c, d
High Level Output Voltage	V_{OH}	—	V_{CC}	—	V	$I_O = 0$ mA, $I_F = 10$ mA	1	
Low Level Output Voltage	V_{OL}	—	0.07	0.25	V	$I_O = 100$ mA	5, 7, 26	
High Level Supply Current	I_{CCH}	—	1.68	2.5	mA	Rg = 10Ω, Cg = 25 nF, $I_F = 10$ mA,	10, 11	
Low Level Supply Current	I_{CCL}	—	2.0	2.5	mA	Rg = 10Ω, Cg = 25 nF, $I_F = 0$ mA		
Threshold Input Current Low to High	I_{FLH}	0.5	1.5	4.0	mA	Rg = 10Ω, Cg = 25 nF, $V_O > 5V$	12, 13, 29	
Threshold Input Voltage High to Low	V_{FHL}	0.8	—	—	V			
Input Forward Voltage	V_F	1.2	1.55	1.95	V	$I_F = 10$ mA	22	
Temperature Coefficient of Input Forward Voltage	$\Delta V_F/\Delta T_A$	—	−1.7	—	mV/°C			
Input Reverse Breakdown Voltage	BV_R	5	—	—	V	$I_R = 100$ µA		
Input Capacitance	C_{IN}	—	70	—	pF	f = 1 MHz, $V_F = 0V$		
UVLO Threshold	V_{UVLO+}	11.0	12.3	13.5	V	$V_O > 5V$, $I_F = 10$ mA	30	
	V_{UVLO-}	9.5	10.7	12.0				
UVLO Hysteresis	$UVLO_{HYS}$	—	1.4	—				

a. Maximum pulse width = 50 µs.

b. Maximum pulse width = 10 µs.

c. In this test, V_{OH} is measured with a DC load current. When driving capacitive loads, V_{OH} will approach V_{CC} as I_{OH} approaches 0 amps.

d. Maximum pulse width = 1 ms.

Switching Specifications (AC)

Unless otherwise noted, all typical values are at $T_A = 25°C$, $V_{CC} - V_{EE} = 30V$, V_{EE} = Ground; all Minimum/Maximum specifications are at recommended operating conditions ($T_A = -40°C$ to $105°C$, $I_{F(ON)} = 7$ mA to 16 mA, $V_{F(OFF)} = -3.6V$ to 0.8V, $V_{CC} = 15V$ to 30V, V_{EE} = Ground)

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions	Figure	Note
Propagation Delay Time to High Output Level	t_{PLH}	0.100	0.260	0.350	µs	Rg = 10 Ω, Cg = 25 nF, f = 20 kHz , Duty Cycle = 50%, I_F = 7 mA to 16 mA, V_{CC} = 15V to 30V	17, 18, 19, 20, 21, 31	a
Propagation Delay Time to Low Output Level	t_{PHL}	0.050	0.145	0.250	µs			
Propagation Delay Difference Between Any Two Parts	PDD ($t_{PHL} - t_{PLH}$)	−0.010	−0.100	−0.200	µs		39, 40	b
Rise Time	t_R	—	22	—	ns	V_{CC} = 30V	31	
Fall Time	t_F	—	18	—	ns			
Output High Level Common Mode Transient Immunity	$|CM_H|$	40	50	—	kV/µs	T_A = 25 °C, I_F = 10 mA, V_{CC} = 30V, V_{CM} = 1500V with split resistors	32	c, d
		25	35	—		T_A = 25 °C, I_F = 10 mA, V_{CC} = 30V, V_{CM} = 1000V without split resistors		
Output Low Level Common Mode Transient Immunity	$|CM_L|$	40	50	—	kV/µs	T_A = 25 °C, V_F = 0V, V_{CC} = 30V, V_{CM} = 1500V with split resistors,	32	c, e
		25	35	—		T_A = 25 °C, V_F = 0V, V_{CC} = 30V, V_{CM} = 1000V without split resistors		

a.   This load condition approximates the gate load of a 1200V/150A IGBT.

b.   The difference between t_{PHL} and t_{PLH} between any two ACPL-H342 parts under the same test condition.

c.   Pins 2 and 4 need to be connected to LED common.

d.   Common mode transient immunity in the high state is the maximum tolerable dV_{CM}/dt of the common mode pulse, V_{CM}, to assure that the output will remain in the high state (that is, $V_O > 15.0V$).

e.   Common mode transient immunity in a low state is the maximum tolerable dV_{CM}/dt of the common mode pulse, V_{CM}, to assure that the output will remain in a low state (that is, $V_O < 1.0V$).

Package Characteristics

Unless otherwise noted, all typical values are at T_A = 25 °C; all Minimum/Maximum specifications are at recommended operating conditions.

Parameter	Symbol	Device	Min.	Typ.	Max.	Units	Test Conditions	Figure	Note
Input-Output Momentary Withstand Voltage[a]	V_{ISO}	ACPL-H342	3750	—	—	V_{RMS}	R_H < 50%, t = 1 min., T_A = 25°C		b, c
		ACPL-K342	5000	—	—	V_{RMS}	R_H < 50%, t = 1 min., T_A = 25°C		c, d
Input-Output Resistance	R_{I-O}		—	> 50^{12}	—	Ω	V_{I-O} = 500 VDC		c
Input-Output Capacitance	C_{I-O}		—	0.2	—	pF	f =1 MHz		
LED-to-Ambient Thermal Resistance	R_{11}		—	145	—	°C/W	Thermal Model in Application Notes Below		e
LED-to-Detector Thermal Resistance	R_{12}, R_{21}		—	25, 38	—				
Detector-to-Ambient Thermal Resistance	R_{22}		—	46	—				

a. The input-output momentary withstand voltage is a dielectric voltage rating that should not be interpreted as an input-output continuous voltage rating. For the continuous voltage rating, refer to your equipment level safety specification or Broadcom Application Note 1074, *Optocoupler Input-Output Endurance Voltage*.

b. In accordance with UL1577, each optocoupler is proof tested by applying an insulation test voltage ≥ 4500 Vrms for 1 second leakage detection current limit, I_{I-O} ≤ 5 mA).

c. Device considered a two-terminal device: pins 1, 2, 3, and 4 shorted together and pins 5, 6, 7, and 8 shorted together.

d. In accordance with UL1577, each optocoupler is proof tested by applying an insulation test voltage ≥ 6000 Vrms for 1 second (leakage detection current limit, I_{I-O} ≤ 5 mA).

e. The device was mounted on a high conductivity test board as per JEDEC 51-7.

Figure 1 High Output Rail Voltage vs. Temperature

$I_F = 10$ mA
$V_{CC} = 30$ V
$V_{EE} = 0$ V

V_{OH} - HIGH OUTPUT RAIL VOLTAGE - V
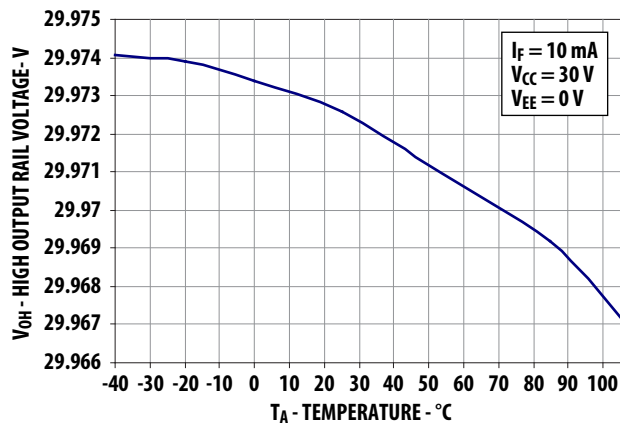
T_A - TEMPERATURE - °C

Figure 2 V_{OH} vs. Temperature

$I_F = 10$ mA
$I_{OUT} = -100$ mA
$V_{CC} = 15$ to 30 V
$V_{EE} = 0$ V

$(V_{OH} - V_{CC})$ - HIGH OUTPUT VOLTAGE DROP - V
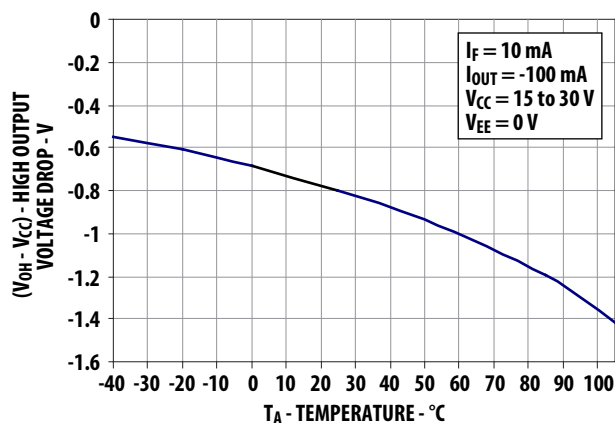
T_A - TEMPERATURE - °C

Figure 3 I_{OH} vs. Temperature

$I_F = 10$ mA
$V_{OUT} = (V_{CC} - 4$ V$)$
$V_{CC} = 15$ to 30 V
$V_{EE} = 0$ V

I_{OH} - OUTPUT HIGH CURRENT - A

T_A - TEMPERATURE - °C

Figure 4 I_{OH} vs. V_{OH}

$T_A = 25$°C

I_{OH} - OUTPUT HIGH CURRENT - A

$(V_{OH} - V_{CC})$ - HIGH OUTPUT VOLTAGE DROP - V
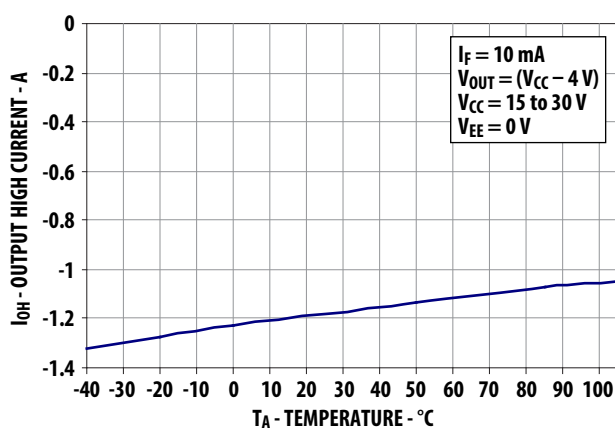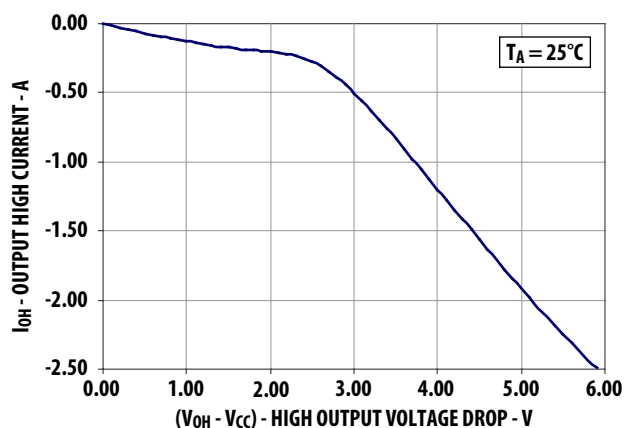
Figure 5 V_{OL} vs. Temperature

$V_{F(OFF)} = 0$ V
$I_{OUT} = 100$ mA
$V_{CC} = 15$ to 30 V
$V_{EE} = 0$ V

V_{OL} - OUTPUT LOW VOLTAGE - V
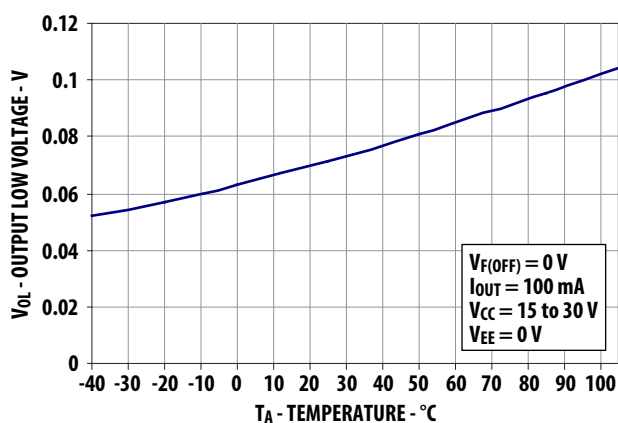
T_A - TEMPERATURE - °C

Figure 6 I_{OL} vs. Temperature

$V_{F(OFF)} = 0$ V
$V_{OUT} = 2.5$ V
$V_{CC} = 15$ to 30 V
$V_{EE} = 0$ V

I_{OL} - OUTPUT LOW CURRENT - A

T_A - TEMPERATURE - °C

Figure 7 I_{OL} vs. V_{OL}

$T_A = 25°C$
$V_{F(OFF)} = 0$ V
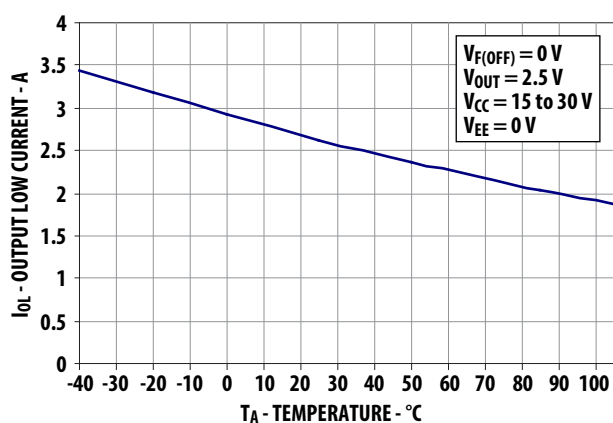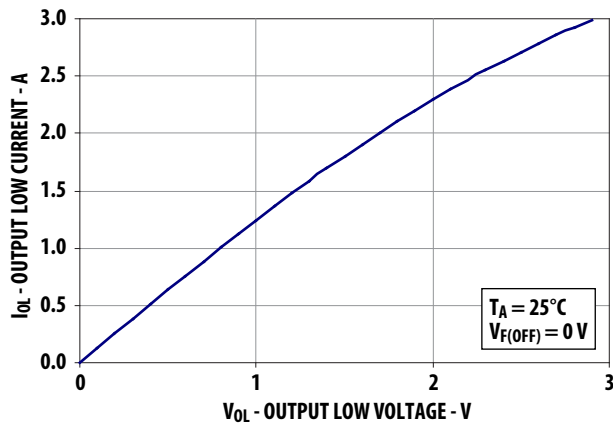
Figure 8 $R_{DS,OH}$ vs. Temperature

$I_F = 10$ mA
$I_{OUT} = -2$ A
$V_{CC} = 15$ to 30 V
$V_{EE} = 0$ V
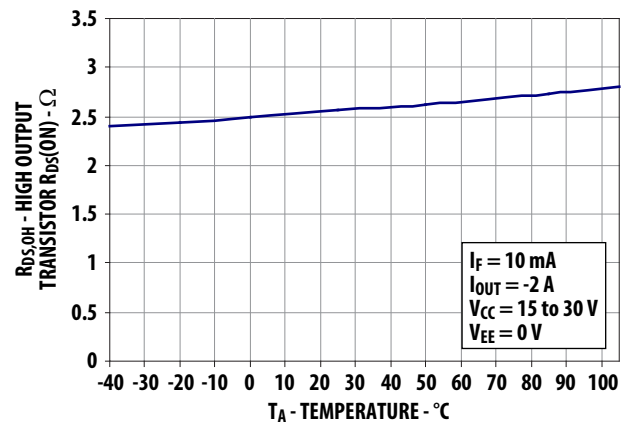
Figure 9 $R_{DS,PL}$ vs. Temperature

$V_{F(OFF)} = 0$ V
$I_{OUT} = 2$ A
$V_{CC} = 15$ to 30 V
$V_{EE} = 0$ V
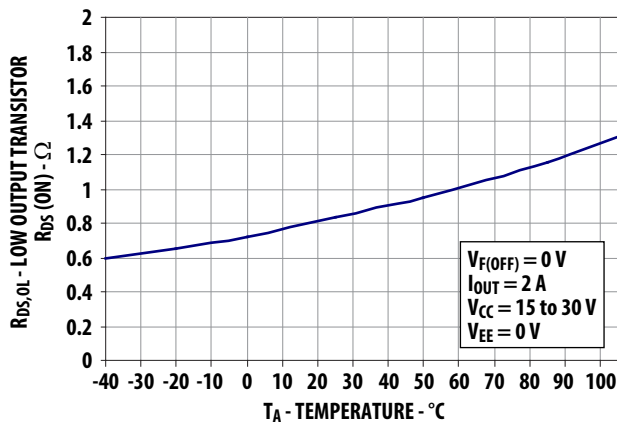
Figure 10 I_{CC} vs. Temperature

$I_F = 10$ mA for I_{CCH}
$I_F = 0$ mA for I_{CCL}
$V_{CC} = 30$ V
$V_{EE} = 0$ V

- - - I_{CCH}
——— I_{CCL}

Figure 11 I_{CC} vs. V_{CC}

$I_F = 10$ mA for I_{CCH}
$I_F = 0$ mA for I_{CCL}
$T_A = 25°C$
$V_{EE} = 0$ V

- - - I_{CCH}
——— I_{CCL}
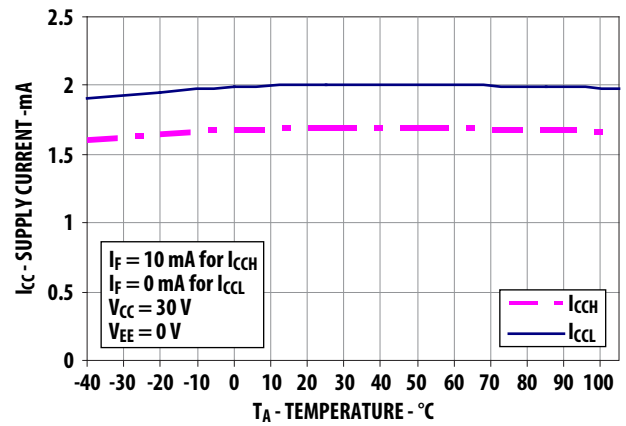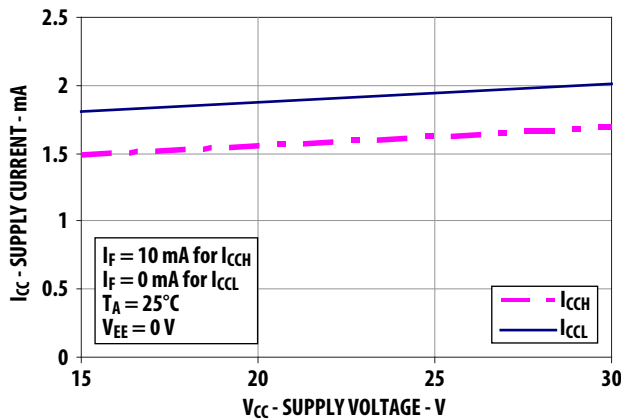
Figure 12 I_{FLH} Hysteresis

$T_A = 25°C$
$V_{CC} = 30$ V
$V_{EE} = 0$ V

——— I_{FLH} ON
- - - I_{FLH} OFF
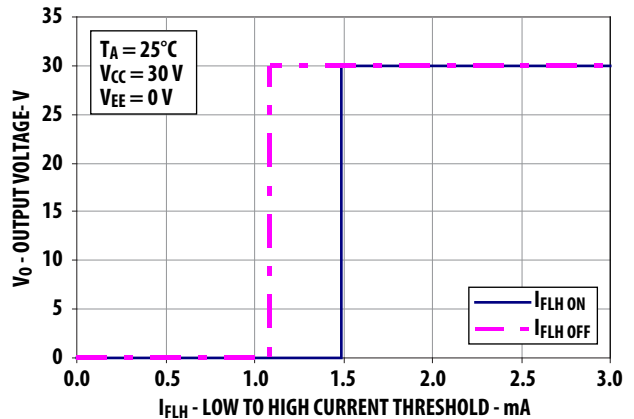
Figure 13 I_{FLH} vs. Temperature
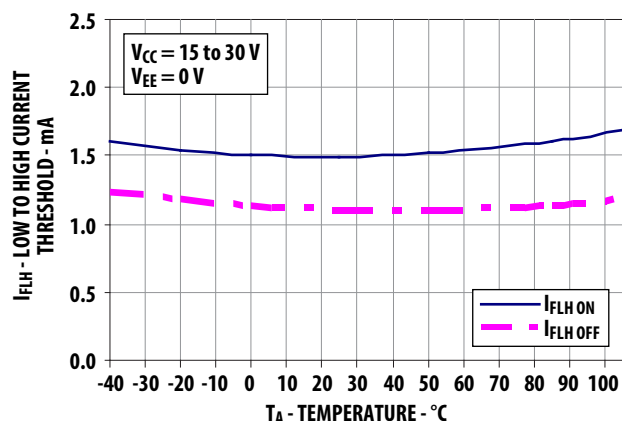
Figure 14 I_{CLAMP} vs. Temperature
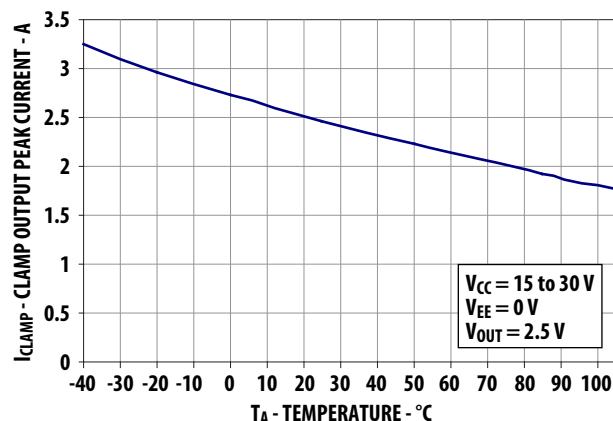
Figure 15 V_{tCLAMP} vs. Temperature
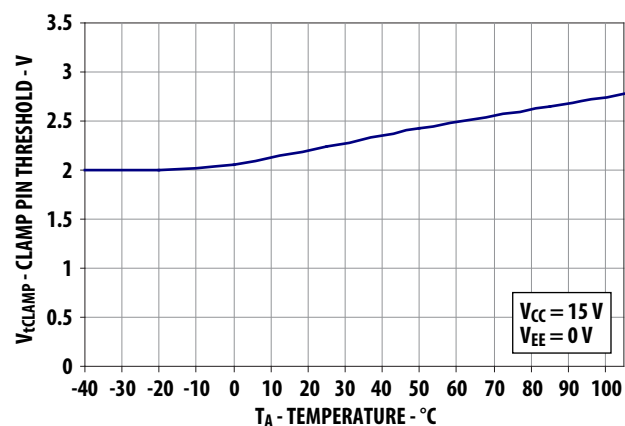
Figure 16 I_{CLAMP} vs. V_{tCLAMP}
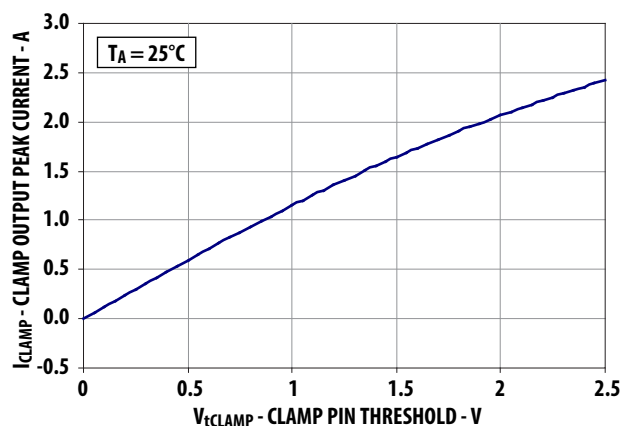
Figure 17 Propagation Delay vs. V_{CC}
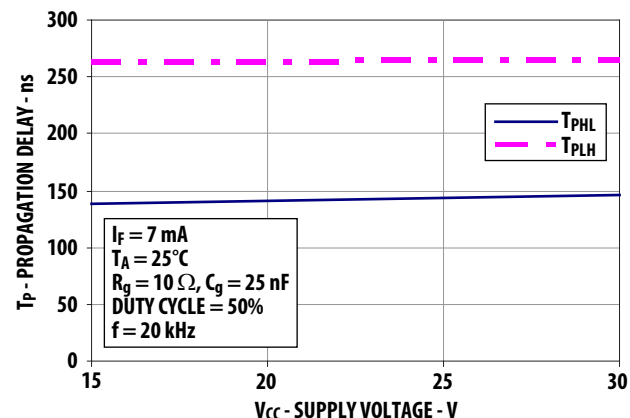
Figure 18 Propagation Delay vs. I_F
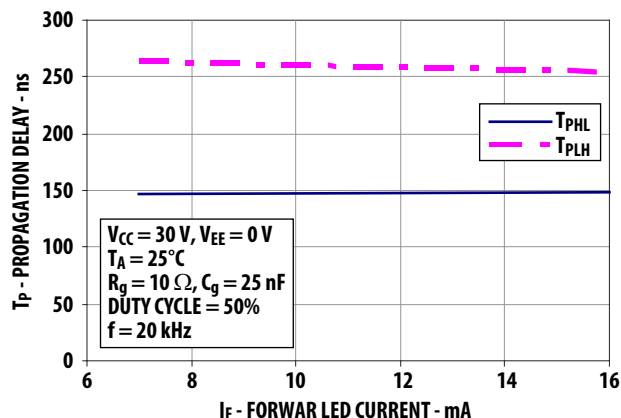
Figure 19 Propagation Delay vs. Temperature
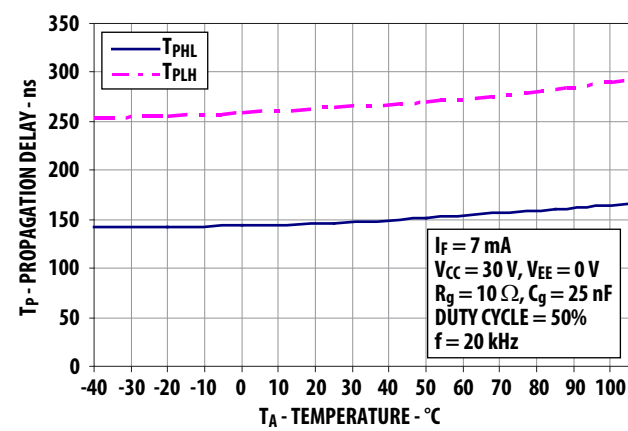
Figure 20 Propagation Delay vs. Rg
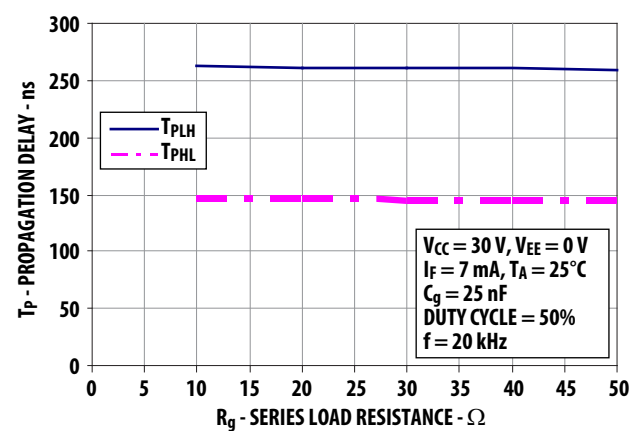
Figure 21 Propagation Delay vs. Cg
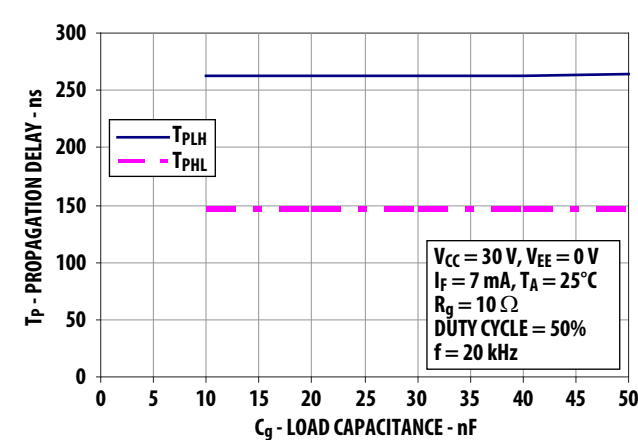
Figure 22 Input Current vs. Forward Voltage
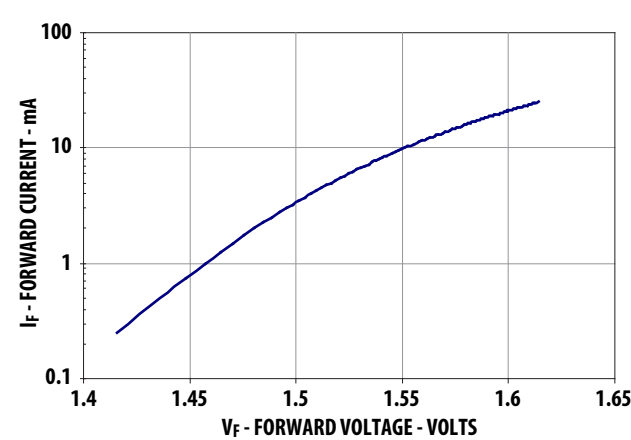
Figure 23 I_{OH} Test Circuit
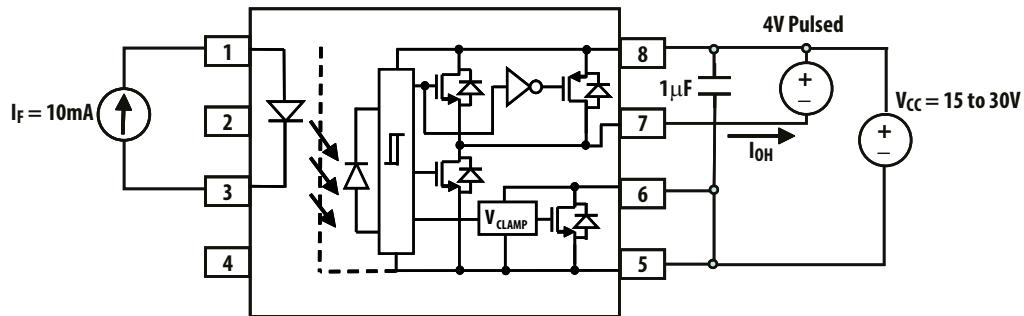
Figure 24 I_{OL} Test Circuit
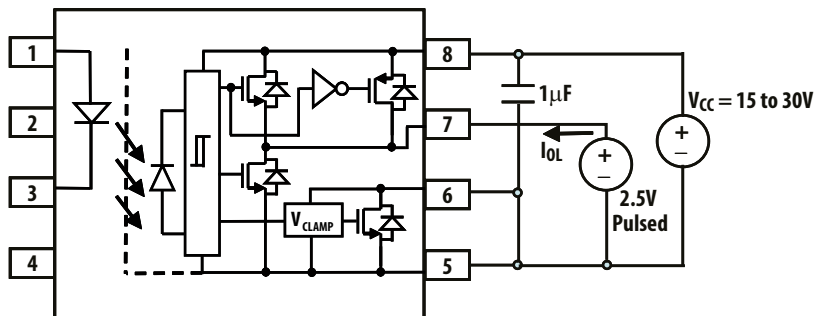
Figure 25 V_{OH} Test Circuit
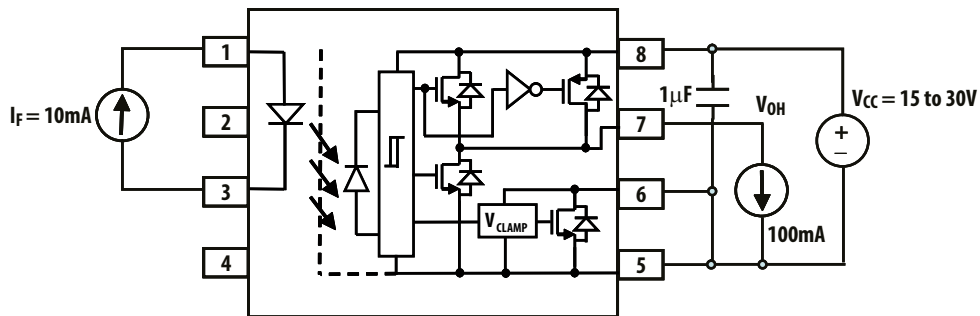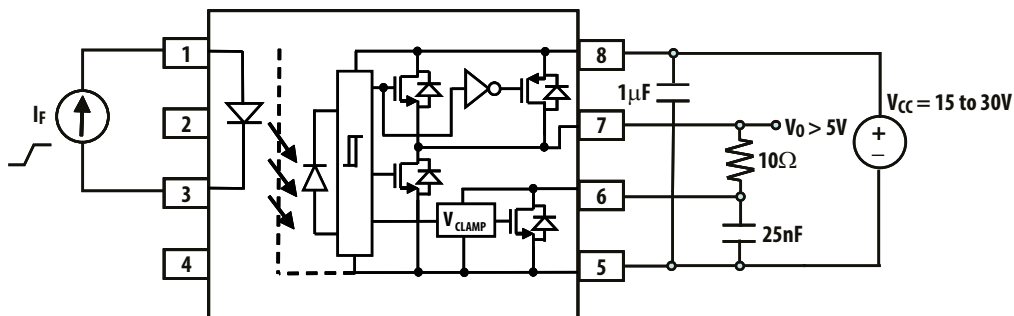

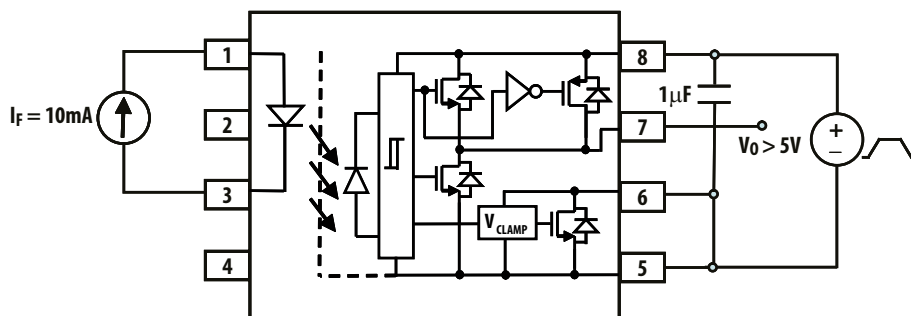
Figure 26 V_{OL} Test Circuit
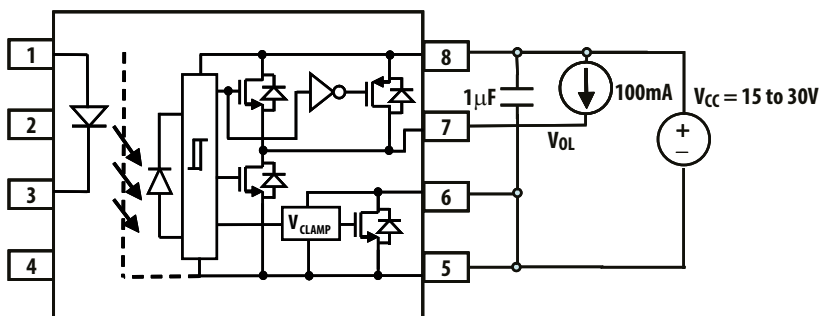
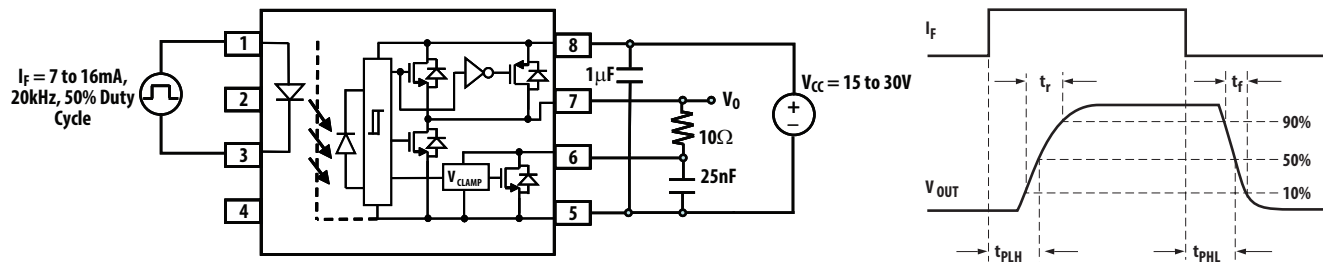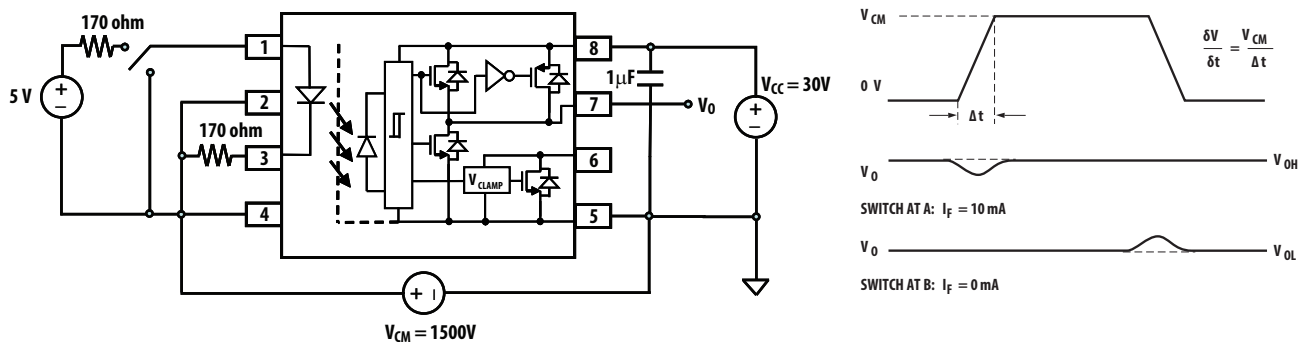**Figure 27 I$_{CLAMP}$ Test Circuit**
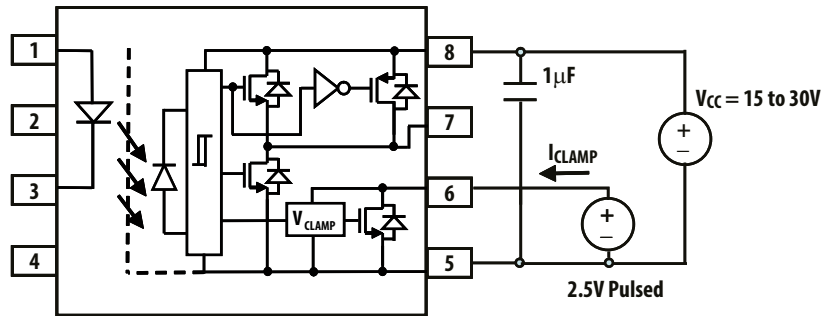
Figure 28 V$_{tCLAMP}$ Test Circuit
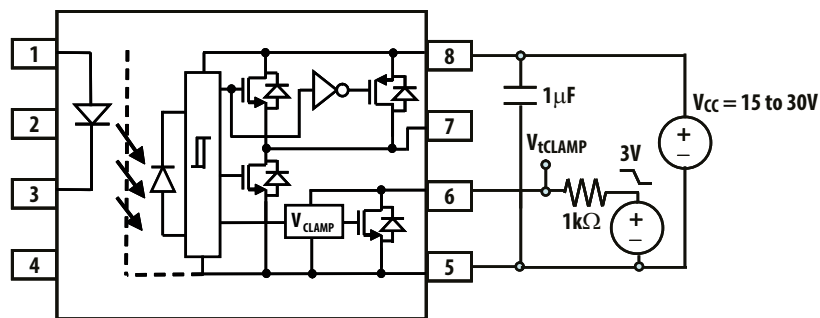
Figure 29 I$_{FLH}$ Test Circuit

Figure 30 UVLO Test Circuit

Figure 31 T$_{PLH}$, t$_{PHL}$, tr, and tf Test Circuit and Waveforms

Figure 32 CMR Test Circuit with Split Resistors Network and Waveforms

Application Information

Product Overview Description

The ACPL-H342/K342 is an optically isolated power output stage capable of driving IGBTs of up to 150A and 1200V. It has very high CMR rating which allows the microcontroller and the IGBT to operate at very large common mode noise found in industrial motor drives and other power switching applications. And to achieve better system reliability in such noisy environment, this power control device incorporates new features like active Miller clamp, rail-to-rail output voltage, anti-cross conduction and LED input current hysteresis.

The active Miller clamp function eliminates the need of negative gate drive in most application and allows the use of simple bootstrap supply for high side driver. Rail-to-rail output voltage ensures that the IGBT's gate voltage is driven to the optimum intended level with no power loss across IGBT. Anti-cross conduction prevents current shoot through between the high and low side of half bridge IGBT configuration. This will help to simplify the controller design in terms of having to account for the delay needed at the LED input. And lastly, the LED input current hysteresis prevents output oscillation if insufficient LED driving current is applied. This will eliminates the need of additional Schmitt trigger circuit at the input LED.

This feature rich IGBT gate driver is designed to increase the performance and reliability of a motor drive without the cost, size, and complexity of external circuitry or control.

Recommended Application Circuit

The recommended application circuit shown in Figure 33 illustrates a typical gate drive implementation using the ACPL-H342. The following describes about driving IGBT. However, it is also applicable to MOSFET. Designers will need to adjust the V$_{CC}$ supply voltage, depending on the MOSFET or IGBT gate threshold requirements (recommended V$_{CC}$ = 18V for IGBT and 12V for MOSFET).

The supply bypass capacitors (1 µF) provide the large transient currents necessary during a switching transition. Because of the transient nature of the charging currents, a low current (2.5mA) power supply will be enough to power the device. The split resistors across the LED will provide a high CMR response by providing a balanced resistance network across the LED.

The gate resistor R$_G$ serves to limit gate charge current and controls the IGBT collector voltage rise and fall times.

In PC board design, care should be taken to avoid routing the IGBT collector or emitter traces close to the ACPL-H342 input as this can result in unwanted coupling of transient signals into ACPL-H342 and degrade performance.

Figure 33 Recommended Application Circuit with Split Resistors LED Drive and Active Miller Clamp
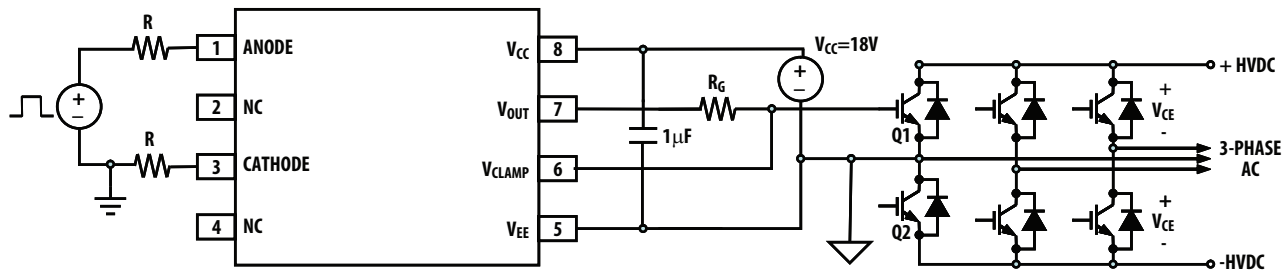
Active Miller Clamp

A Miller clamp allows the control of the Miller current during a high dV/dt situation. And it can also eliminate the use of a negative supply voltage by quickly discharging the large gate capacitance of IGBT to low level without affecting the IGBT turn-off characteristics. During turn-off, the gate voltage is monitored and the clamp output is activated when gate voltage goes below 2.3V (relative to VEE). The clamp voltage is V_{OL} + 2.5V typ for a Miller current up to 2.5A. The clamp is disabled when the LED input is triggered again.

The AN5314 application note describes how the clamp reduces the parasitic turn-on effect due to the Miller capacitor and at the same time eliminates the need of a negative power supply.

The Miller pin should be connected to V_{EE} when not in use.

Rail-to-Rail Output

Figure 34 shows a typical gate driver's high current output stage with three bipolar transistors in darlington configuration. During the output high transition, the output voltage rises rapidly to within three diode drops of V_{CC}. To ensure the V_{OUT} is at V_{CC} in order to achieve IGBT rated $V_{CE(ON)}$ voltage. The level of V_{CC} will be need to be raised to beyond $V_{CC} + 3(V_{BE})$ to account for the diode drops. And to limit the output voltage to V_{CC}, a pull-down resistor, RPULL-DOWN between the output and V_{EE} is recommended to sink a static current while the output is high.

ACPL-H342 uses a power NMOS follower stage to deliver the initial large current and a smaller PMOS to pull it to V_{CC} to achieve rail-to-rail output voltage as shown in Figure 35. This ensures that the IGBT's gate voltage is driven to the optimum intended level with no power loss across IGBT even when an unstable power supply is used.

Figure 34 Typical Gate Drive with Output Stage in Darlington Configuration
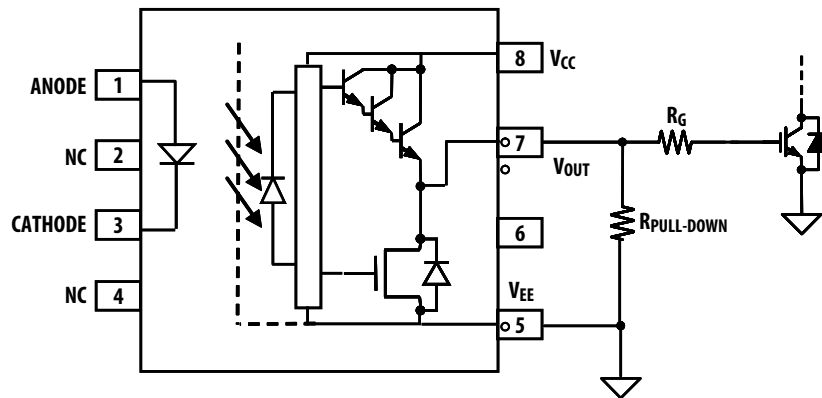
Figure 35 ACP-H342 with NMOS and PMOS Output Stage for Rail-to-Rail Output Voltage
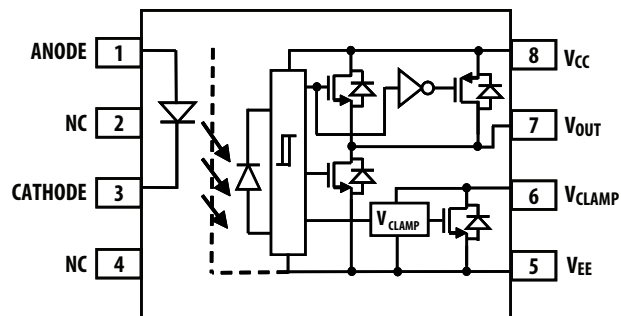
Selecting the Gate Resistor (Rg)

Step 1: Calculate Rg minimum from the I_{OL} peak specification. The IGBT and Rg in Figure 33 can be analyzed as a simple RC circuit with a voltage supplied by ACPL-H342/K342.

$$Rg \geq \frac{V_{CC} - V_{EE} - V_{OL}}{I_{OLPEAK}}$$

$$= \frac{18V - 0V - 2.3V}{2.5A}$$

$$= 6.28\Omega \approx 7\Omega$$

The V_{OL} value of 2.3V in the previous equation is the V_{OL} at the peak current of 2.5A (see Figure 7).

Step 2: Check the ACPL-H342/K342 power dissipation and increase Rg if necessary. The ACPL-H342/K342 total power dissipation (P_T) is equal to the sum of the emitter power (P_E) and the output power (P_O).

$$P_T \quad = P_E + P_O$$
$$P_E \quad = I_F \times V_F \times \text{Duty Cycle}$$
$$P_O \quad = P_{O(BIAS)} + P_{O(SWITCHING)}$$
$$\quad\quad = I_{CC} \times (V_{CC} - V_{EE}) + E_{SW}(Rg;Qg) \times f$$

Using I_F(worst case) = 16 mA, Rg = 7Ω, Max Duty Cycle = 80%, Qg = 500 nC, f = 25 kHz and T_A max = 85°C:

$$P_E \quad = 16\ mA \times 1.95V \times 0.8 = 25\ mW$$
$$P_O \quad = 2.5\ mA \times 18V + 4\mu J \times 25\ kHz$$
$$\quad\quad = 45\ mW + 100\ mW$$
$$\quad\quad = 145\ mW < 500\ mW\ (P_{O(MAX)}\ @\ 85°C)$$

The value of 2.5mA for I_{CC} in the previous equation is the maximum I_{CC} over the entire operating temperature range.

Since P_O is less than $P_{O(MAX)}$, Rg = 7Ω is alright for the power dissipation.

Figure 36 Energy Dissipated in the ACPL-H342/K342 for Each IGBT Switching Cycle
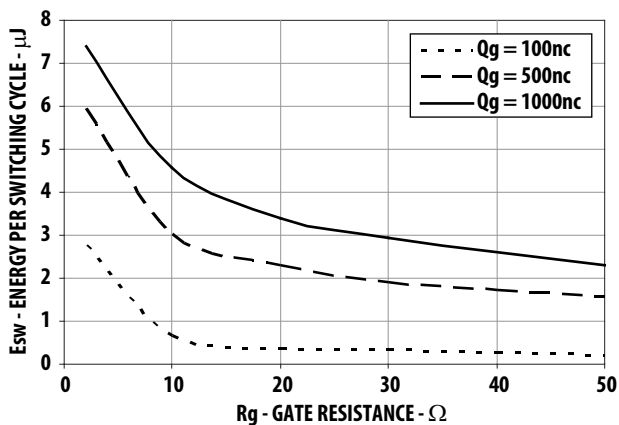
Anti-Cross Conduction to Prevent Current Shoot Through and Determining Dead Time

The ACPL-H342 includes a Propagation Delay Difference (PDD = $t_{PHL} - t_{PLH}$) specification to help prevent both the high(Q1) and low(Q2) side power transistors from turning on at the same time. This "Anti-Cross" conduction feature prevents large currents from flowing through the power transistors by ensuring t_{PHLMAX} is faster than t_{PLHMIN}. In another words, the "Anti-Cross" feature will ensure one power transistor is turned off before the other is turned on.

A gate driver without Anti-Cross feature will for example has a PDD_{MIN} of –350 ns and a PDD_{MAX} of 350 ns. A positive PDD_{MAX} of 350 ns would mean one transistor will be turn on before the other is off since $tPHL_{MAX}$ is longer than $tPLH_{MIN}$. This is shown in Figure 37. To prevent this and the shoot through current, the turn on of LED2 should be delayed (relative to the turn off of LED1) so that under worst-case conditions, Q1 has just turned off when Q2 turns on. The amount of delay to achieve this condition is equal to PDD_{MAX} as shown in Figure 38.
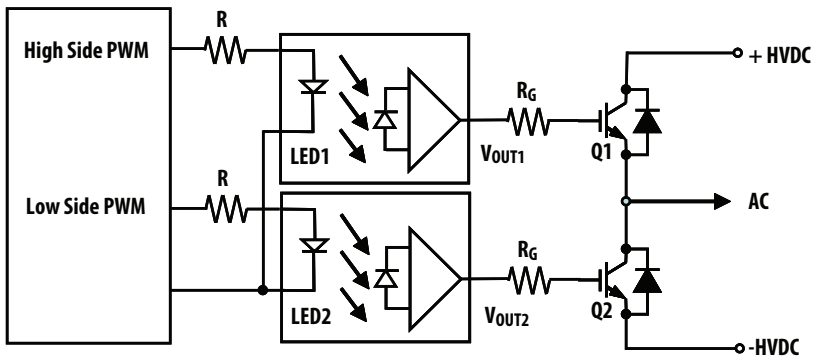

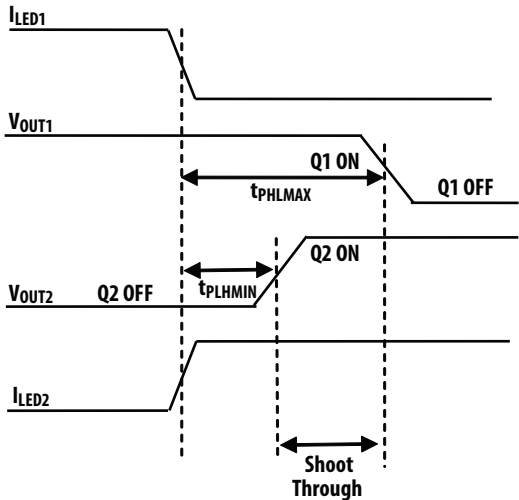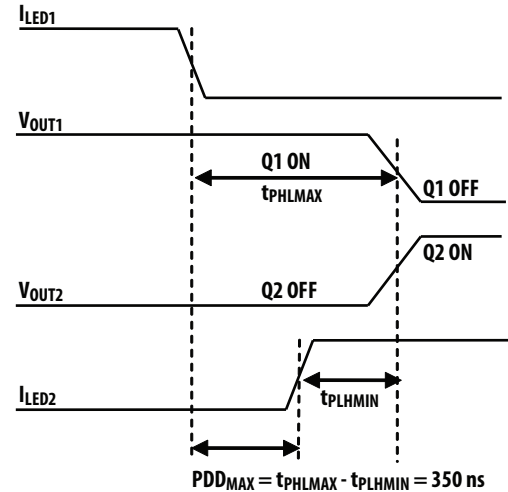**Figure 37 Current Shoot Through without Anti-Cross Feature**

Figure 38 Adding Delay to Prevent Shoot Through

The ACPL-H342 with the Anti-Cross feature has a PDD_{MIN} of –10 ns and a PDD_{MAX} of –200 ns. Since the PDD is always a negative value, the t_{PHLMAX} is always faster than t_{PLHMIN}. Thus this simplified the design without having to add any amount of delay for the input LEDs as shown in Figure 39.

Symbol	Min.	Typ.	Max.	Units
t_{PLH}	0.100	0.260	0.350	µs
t_{PHL}	0.050	0.145	0.250	µs
PDD ($t_{PHL} - t_{PLH}$)	–0.010	–0.100	–0.200	µs

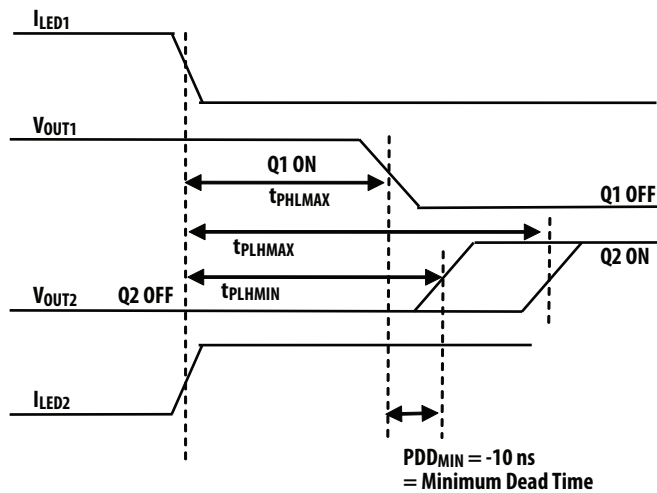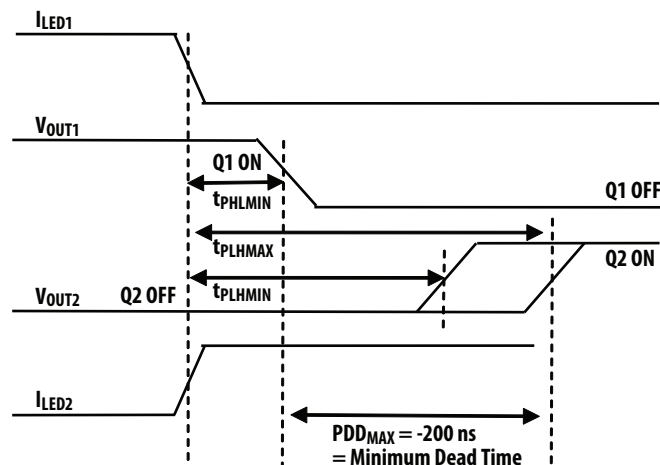**Figure 39 Anti-Cross to Prevent Shoot Through**

Figure 40 Determining Maximum Dead Time

Dead time is the time period during which both the high(Q1) and low(Q2) side transistor are off. During this time, no work is done and this reduces the efficiency of the inverter or motor drive. The minimum and maximum dead time is shown in Figure 39 and Figure 40 and is equivalent to the PDD_{MIN} and PDD_{MAX}. Due to the smaller PDD and skewed propagation delay configuration, ACPL-H342 shows a smaller maximum dead time as compared to its predecessor, HCPL-3120 as shown in Figure 41 and hence an improve in efficiency. Note that the propagation delays used to calculate PDD and dead time are taken at equal temperature and test conditions since the optocouplers under consideration are typically mounted in close proximity to each other and are switching identical IGBTs.

Figure 41 HCPL-3120 Maximum Dead Time
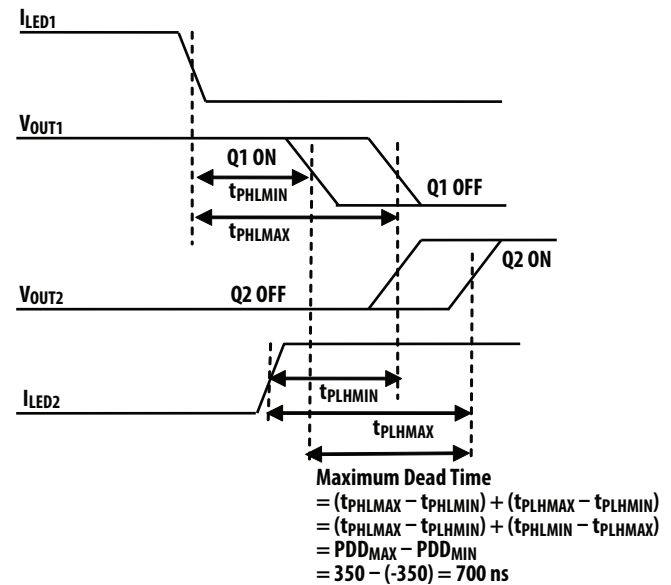
LED Input Current Hysteresis

The detector has optical receiver input stage with built-in Schmitt trigger to provide logic compatible waveforms, eliminating the need for additional wave shaping. The hysteresis (Figure 12) provides differential mode noise immunity and minimizes the potential for output signal chatter.

Under Voltage Lockout

The ACPL-H342 under voltage lockout (UVLO) feature is designed to prevent the application of insufficient gate voltage to the IGBT by forcing the ACPL-H342 output low during power-up. IGBTs typically require gate voltages of 15V to achieve their rated $V_{CE(ON)}$ voltage. At gate voltages below 13V typically, the $V_{CE(ON)}$ voltage increases dramatically, especially at higher currents. At very low gate voltages (below 10V), the IGBT may operate in the linear region and quickly overheat. The UVLO function causes the output to be clamped whenever insufficient operating supply (V_{CC}) is applied. Once V_{CC} exceeds V_{UVLO+} (the positive-going UVLO threshold), the UVLO clamp is released to allow the device output to turn on in response to input signals.

Thermal Model for ACPL-H342/K342 Stretched SO8 Package Optocoupler

Definitions:

R_{11}: Junction to Ambient Thermal Resistance of LED due to heating of LED.

R_{12}: Junction to Ambient Thermal Resistance of LED due to heating of Detector (Output IC).

R_{21}: Junction to Ambient Thermal Resistance of Detector (Output IC) due to heating of LED.

R_{22}: Junction to Ambient Thermal Resistance of Detector (Output IC) due to heating of Detector (Output IC).

P_1: Power dissipation of LED (W).

P_2: Power dissipation of Detector/Output IC (W).

T_1: Junction temperature of LED (°C).

T_2: Junction temperature of Detector (°C).

T_A: Ambient temperature.

Ambient Temperature: Junction to ambientthermal resistances were measured approximately 1.25 cm above optocoupler at ~23°C in still air.

Thermal Resistance	°C/W
R_{11}	145
R_{12}, R_{21}	25, 38
R_{22}	46

This thermal model assumes that an 8-pin single-channel plastic package optocoupler is soldered into a 7.62 cm × 7.62 cm printed circuit board (PCB) per JEDEC standards. The temperature at the LED and Detector junctions of the optocoupler can be calculated using the equations below.

$$T_1 = (R_{11} \times P_1 + R_{12} \times P_2) + T_A \qquad (1)$$
$$T_2 = (R_{21} \times P_1 + R_{22} \times P_2) + T_A \qquad (2)$$

Using the given thermal resistances and thermal model formula in this data sheet, we can calculate the junction temperature for both LED and the output detector. Both junction temperature should be within the absolute maximum rating.

For example, given $P_1 = 45$ mW, $P_2 = 210$ mW, $T_a = 85$°C:

LED junction temperature,

$$
\begin{aligned}
T_1 \quad &= (R_{11} \times P_1 + R_{12} \times P_2) + T_A \\
&= (145 \times 0.045 + 25 \times 0.210) + 85 \\
&= 97°C
\end{aligned}
$$

Output IC junction temperature,

$$
\begin{aligned}
T_2 \quad &= (R_{21} \times P_1 + R_{22} \times P_2) + T_A \\
&= (38 \times 0.045 + 46 \times 0.210) + 85 \\
&= 96°C
\end{aligned}
$$

T_1 and T_2 should be limited to 125°C based on the board layout and part placement.

Related Application Notes

AN5336 – *Gate Drive Optocoupler Basic Design for IGBT/MOSFET*

AN1043 – *Common-Mode Noise: Sources and Solutions*

AN02-0310EN – *Plastics Optocouplers Product ESD and Moisture Sensitivity*

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